#### MSA-0386

# Cascadable Silicon Bipolar MMIC Amplifier

# AVAGO

# **Data Sheet**

#### **Description**

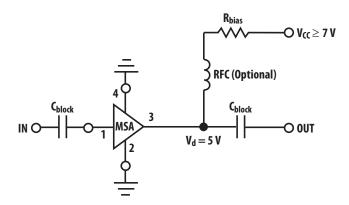
The MSA-0386 is a high performance silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a low cost, surface mount plastic package. This MMIC is designed for use as a general purpose 50  $\Omega$  gain block. Typical applications include narrow and broad band IF and RF amplifiers in commercial and industrial applications.

The MSA-series is fabricated using Avago's 10 GHz  $f_T$ , 25 GHz  $f_{MAX}$ , silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metalization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

#### **86 Plastic Package**



**Typical Biasing Configuration** 



#### **Features**

- Lead-free Option Available
- Cascadable 50  $\Omega$  Gain Block
- 3 dB Bandwidth: DC to 2.4 GHz
- 12.0 dB Typical Gain at 1.0 GHz
- 10.0 dBm Typical P<sub>1 dB</sub> at 1.0 GHz
- Unconditionally Stable (k>1)
- Surface Mount Plastic Package
- Tape-and-Reel Packaging Option Available

### **MSA-0386 Absolute Maximum Ratings**

Parameter	Absolute Maximum <sup>[1]</sup>
Device Current	70 mA
Power Dissipation [2, 3]	400 mW
RF Input Power	+13 dBm
Junction Temperature	150° C
Storage Temperature	-65 to 150° C

Thermal Resistance [2]:	
$\theta_{jc} = 115$ °C/W	

- 1. Permanent damage may occur if any of these limits are exceeded.
- T<sub>CASE</sub> = 25° C.
  Derate at 9.5 mW/°C for T<sub>C</sub> > 116° C.

# Electrical Specifications<sup>[1]</sup>, $T_A = 25^{\circ}$ C

Symbol	Parameters and Test Conditions: I <sub>d</sub> = 35 mA, Z <sub>0</sub> = 50 $\Omega$			Min.	Тур.	Max.
G <sub>P</sub>	Power Gain ( S <sub>21</sub>   <sup>2</sup> )	f = 0.1 GHz	dB		12.5	
		f = 1.0 GHz		10.0	12.0	
$\Delta G_P$	Gain Flatness	f = 0.1 to 1.6 GHz	dB		+0.7	
f <sub>3 dB</sub>	3 dB Bandwidth <sup>[2]</sup>		GHz		2.4	
VSWR	Input VSWR	f = 0.1 to $3.0$ GHz			1.5:1	
	Output VSWR	f = 0.1 to 3.0 GHz			1.7:1	
NF	50 $\Omega$ Noise Figure	f = 1.0 GHz	dB		6.0	
P <sub>1dB</sub>	Output Power at 1 dB Gain Compression	f = 1.0 GHz	dBm	dBm		
IP <sub>3</sub>	Third Order Intercept Point	f = 1.0 GHz	dBm		23.0	
t <sub>D</sub>	Group Delay	f = 1.0 GHz	psec		140	
V <sub>d</sub>	Device Voltage		V	4.0	5.0	6.0
dV/dT	Device Voltage Temperature Coefficient		mV/°C		-8.0	

#### Notes:

### **Ordering Information**

Part Numbers	No. of Devices	Comments
MSA-0386-BLK	100	Bulk
MSA-0386-BLKG	100	Bulk
MSA-0386-TR1	1000	7" Reel
MSA-0386-TR1G	1000	7" Reel
MSA-0386-TR2	4000	13" Reel
MSA-0386-TR2G	4000	13" Reel

Note: Order part number with a "G" suffix if lead-free option is desired.

<sup>1.</sup> The recommended operating current range for this device is 20 to 40 mA. Typical performance as a function of current is on the following page.

MSA-0386 Typical Scattering Parameters (Z $_0$  = 50  $\Omega$  ,  $T_A$  = 25° C,  $I_d$  = 35 mA)

Freq. GHz	S <sub>11</sub>		S <sub>21</sub>		S <sub>12</sub>	S <sub>12</sub>			S <sub>22</sub>	
	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang
0.1	0.11	174	12.5	4.22	175	-18.3	0.122	1	0.13	-11
0.2	0.11	169	12.5	4.20	170	-18.2	0.124	2	0.13	-20
0.4	0.11	159	12.4	4.16	159	-18.1	0.124	5	0.14	-41
0.6	0.10	149	12.2	4.09	149	-17.9	0.128	8	0.15	-60
0.8	0.10	142	12.1	4.00	139	-17.6	0.131	9	0.16	-78
1.0	0.09	137	11.9	3.93	129	-17.4	0.136	11	0.18	-93
1.5	0.09	139	11.2	3.61	106	-16.6	0.149	14	0.20	-129
2.0	0.12	149	10.3	3.28	83	-15.3	0.171	13	0.23	-157
2.5	0.18	150	9.4	2.95	66	-14.4	0.190	12	0.26	-176
3.0	0.25	142	83	2.60	48	-13.7	0.207	9	0.29	167
3.5	0.32	133	7.2	2.29	31	-13.2	0.219	3	0.30	152
4.0	0.40	124	6.0	2.01	15	-13.0	0.224	-1	0.31	142
5.0	0.53	106	3.7	1.53	-13	-12.8	0.228	-11	032	128

# Typical Performance, $T_A = 25^{\circ} C$

(unless otherwise noted)

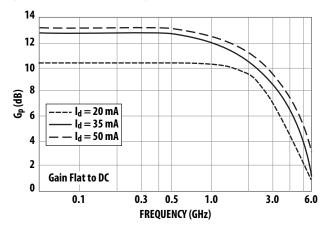


Figure 1. Typical Power Gain vs Frequency,  $T_A = 25^{\circ}$  C.

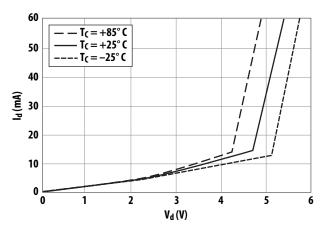


Figure 2. Device Current vs. Voltage.

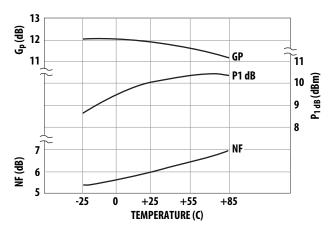


Figure 3. Output Power at 1 dB Gain Compression, NF and Power Gain vs. Case Temperature,  $f=1.0~{\rm GHz}, I_d=35~{\rm mA}.$ 

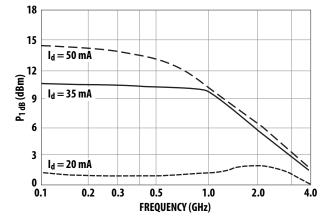


Figure 4. Output Power at 1 dB Gain Compression vs. Frequency.

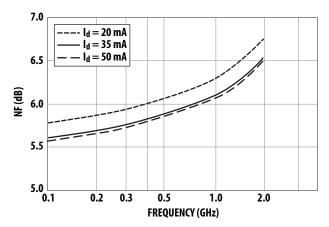
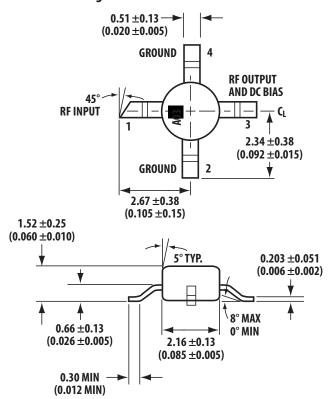


Figure 5. Noise Figure vs. Frequency.

# **86 Plastic Package Dimensions**



Dimensions are in millimeters (inches)

For product information and a complete list of distributors, please go to our web site: **www.avagotech.com** 

